



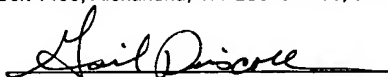
Docket No.: S1022.81021US00
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Daniel Bensahel
Serial No.: 10/614675
Confirmation No.: 7318
Filed: July 7, 2003
For: GROWTH OF A SINGLE-CRYSTAL REGION OF A III-V COMPOUND
ON A SINGLE-CRYSTAL SILICON SUBSTRATE
Examiner: Felisa Carla Hiteshew
Art Unit: 1722

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as First Class Mail, in an envelope addressed to: MS Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the date shown below.

Dated: 8-26-05


Gail Driscoll

AMENDMENT IN RESPONSE TO NON-FINAL OFFICE ACTION

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

In response to the Office Action dated April 28, 2005, please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.